## **Supporting information**

## Multiple Anti-counterfeiting Realized in NaBaScSi<sub>2</sub>O<sub>7</sub> with A

## Single Activator of Eu<sup>2+</sup>

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Fig. S1 SEM images microcrystal particles, the enlarged single particle, EDS elemental mapping of the NaBa<sub>0.975</sub>ScSi<sub>2</sub>O<sub>7</sub>: 0.015Eu<sup>2+</sup>, 0.01Nd<sup>3+</sup>; (b) NaBa<sub>0.9725</sub>ScSi<sub>2</sub>O<sub>7</sub>: 0.015Eu<sup>2+</sup>, 0.0125Pr<sup>3+</sup> for different elements.



Fig. S2 SEM images microcrystal particles, the enlarged single particle and EDS elemental mapping for different elements of the NaBa<sub>0.975</sub>ScSi<sub>2</sub>O<sub>7</sub>: 0.015Eu<sup>2+</sup>, 0.01Nd<sup>3+</sup>; (b) NaBa<sub>0.9725</sub>ScSi<sub>2</sub>O<sub>7</sub>: 0.015Eu<sup>2+</sup>, 0.0125Pr<sup>3+</sup>.



Fig. S3 TL curve of  $NaBa_{0.98}ScSi_2O_7$ :  $0.02Eu^{2+}$  (a); and TL curves of  $NaBaScSi_2O_7$ :  $Eu^{2+}$ ,  $NaBaScSi_2O_7$ :  $Eu^{2+}$ ,  $Nd^{3+}$ ,  $NaBaScSi_2O_7$ :  $Eu^{2+}$ ,  $Pr^{3+}$  (b).



Fig. S4 PL spectra with normalized blue emission (a, c) and normalized green emission (b, d) of NaBa<sub>0.985</sub>.  $_{v}$ ScSi<sub>2</sub>O<sub>7</sub>: 0.015Eu<sup>2+</sup>, yNd<sup>3+</sup> phosphors under the excitation of 290 and 308 nm, respectively.



Fig. S5 PL spectra with normalized blue emission (a, c) and normalized green emission (b, d) of  $NaBa_{0.985-}$ <sub>v</sub>ScSi<sub>2</sub>O<sub>7</sub>: 0.015Eu<sup>2+</sup>, yPr<sup>3+</sup> phosphors under the excitation of 290 and 308 nm, respectively.



Fig. S6 PL, PSL spectra of  $NaBa_{0.975}ScSi_2O_7$ :  $0.015Eu^{2+}$ ,  $0.01Nd^{3+}$  (a); and PL, LPL spectra of  $NaBa_{0.9725}ScSi_2O_7$ :  $0.015Eu^{2+}$ ,  $0.0125Pr^{3+}$  (b).



Fig. S7 TL curves of NaBa<sub>0.975</sub>ScSi<sub>2</sub>O<sub>7</sub>:  $0.015Eu^{2+}$ ,  $0.01Nd^{3+}$  (a) and NaBa<sub>0.9725</sub>ScSi<sub>2</sub>O<sub>7</sub>:  $0.015Eu^{2+}$ ,  $0.0125Pr^{3+}$  (c) under 254 and 365 nm excitation with different irradiation time; TL decay curves of NaBa<sub>0.975</sub>ScSi<sub>2</sub>O<sub>7</sub>:  $0.015Eu^{2+}$ ,  $0.01Nd^{3+}$  (b) and NaBa<sub>0.9725</sub>ScSi<sub>2</sub>O<sub>7</sub>:  $0.015Eu^{2+}$ ,  $0.0125Pr^{3+}$  (d).



Fig. S8 Persistent decay curves (a) and Time dependence of the reciprocal of the persistent luminescence intensity (b) of NaBa<sub>0.975</sub>ScSi<sub>2</sub>O<sub>7</sub>: 0.015Eu<sup>2+</sup>, 0.01Nd<sup>3+</sup> and NaBa<sub>0.9725</sub>ScSi<sub>2</sub>O<sub>7</sub>: 0.015Eu<sup>2+</sup>, 0.0125Pr<sup>3+</sup> after UV light (254 and 365 nm) irradiation for 20 min.

X	0.015	0.02	0.03	0.04	0.045	0.05
τ (421nm)	4.577µs	4.312µs	4.211µs	4.119µs	3.940µs	3.719µs
τ (500nm)	3.151µs	4.216µs	4.477µs	4.715µs	4.781µs	4.839µs

Table S1. The lifetimes of NaBa<sub>1-x</sub>ScSi<sub>2</sub>O<sub>7</sub>: xEu<sup>2+</sup> phosphors.